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10/593,812	09/22/2006	Kouji Nishikawa	296483US0PCT	5609
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ALEAANDKIA	A, VA 22314	ART UNIT		PAPER NUMBER
			1795	
			NOTIFICATION DATE	DELIVERY MODE
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Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

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	Application No.	Applicant(s)
	10/593,812	NISHIKAWA ET AL.
Office Action Summary	Examiner	Art Unit
	ANCA EOFF	1795
The MAILING DATE of this communication ap Period for Reply	opears on the cover sheet with the c	correspondence address
A SHORTENED STATUTORY PERIOD FOR REPL WHICHEVER IS LONGER, FROM THE MAILING ID. - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period. - Failure to reply within the set or extended period for reply will, by statu Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNICATION .136(a). In no event, however, may a reply be tind d will apply and will expire SIX (6) MONTHS from the, cause the application to become ABANDONE	N. mely filed the mailing date of this communication. ED (35 U.S.C. § 133).
Status		
Responsive to communication(s) filed on 11 (2a) This action is FINAL . 2b) ▼ This 3) Since this application is in condition for allowed closed in accordance with the practice under	is action is non-final. ance except for formal matters, pro	
Disposition of Claims		
4) Claim(s) 23-32 is/are pending in the application 4a) Of the above claim(s) is/are withdrays s/are allowed. 5) Claim(s) is/are allowed. 6) Claim(s) 23-32 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/ Application Papers 9) The specification is objected to by the Examination the drawing(s) filed on is/are: a) accept accept	awn from consideration. for election requirement. her. scepted or b) □ objected to by the	
Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct T1) The oath or declaration is objected to by the E	ction is required if the drawing(s) is ob	jected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreig a) All b) Some * c) None of: 1. Certified copies of the priority documer 2. Certified copies of the priority documer 3. Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	nts have been received. nts have been received in Applicat ority documents have been receive au (PCT Rule 17.2(a)).	ion No ed in this National Stage
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail D 5) Notice of Informal F 6) Other:	ate

Application/Control Number: 10/593,812 Page 2

Art Unit: 1795

DETAILED ACTION

1. Claims 23-32 are pending. Claims 1-22 have been canceled.

2. The foreign priority document JP 2004-087520 filed on March 24, 2004 was received and acknowledged. However, in order to benefit of the earlier filing date, a certified English translation is required.

Continued Examination Under 37 CFR 1.114

3. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on July 11, 2008 has been entered.

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 23-25 and 28-29 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hamada et al. (US Pg-Pub 2004/0033438).

Art Unit: 1795

With regard 23, Hamada et al. disclose a positive-working chemically amplified radiation sensitive resin composition which comprises an alkali-insoluble or slightly alkali-soluble resin (A) protected with an acid-labile protecting group and made alkali-soluble by cleavage of said acid-labile protecting group and compounds generating an acid irradiation with radiation (B) and (C) (par.0013). The composition further comprises a solvent (par.0030).

The resin (A) may be a obtained by copolymerizing 4-, 3- or 2-hydroxystyrene protected by the protecting group with another monomer or monomers (par.0017), wherein the other monomers include acrylic esters and their derivatives, methacrylic esters and their derivatives (par.0018), isopropenylphenol (par.0019), N-(4-hydroxyphenyl)(meth)acrylamide, N-(3-hydroxyphenyl) (meth)acrylamide, N-(4-hydroxyphenyl) (meth)acrylamide, N-(4-hydroxybenzyl)(meth)acrylamide, N-(4-hydroxybenzyl)(meth)acrylamide, N-(2-hydroxybenzyl)(meth)acrylamide, N-(2-hydroxybenzyl)(meth)acrylamide (par.0019).

Hamada et al. do not give specific examples of acrylic esters or methacrylic esters used as "other monomers" but the polymer of formula (I) in par.0022 clearly shows t-butyl (meth)acrylate used as "other monomer".

While Hamada et al. do not specifically disclose a copolymer comprising units of isopropenyphenol, t-butyl (meth)acrylate and an unit of N-(4-hydroxyphenyl)(meth)acrylamide, N-(3-hydroxyphenyl) (meth)acrylamide, N-(2-hydroxyphenyl)(meth)acrylamide, N-(4-hydroxybenzyl)(meth)acrylamide, N-(3-hydroxybenzyl)(meth)acrylamide or N-(2-hydroxybenzyl)(meth)acrylamide, it would have been obvious to one of ordinary skill in the art at the time of the

Art Unit: 1795

invention to obtain such a copolymer, based on Hamada's teachings that one or more "other monomers" can be copolymerized with protected hydroxystyrene and such "other monomers" include the derivatives listed above (par.0017-0022).

N-(4-hydroxyphenyl)(meth)acrylamide, N(3-hydroxyphenyl)
(meth)acrylamide and N-(2-hydroxyphenyl)(meth)acrylamide are equivalent to
the unit (1) of the instant application, wherein R_1 is a hydrogen atom or a methyl
group, n=0 and m=0.

N-(4-hydroxybenzyl)(meth)acrylamide, N-(3-hydroxybenzyl)(meth)acrylamide and N-(2-hydroxybenzyl)(meth)acrylamide are equivalent to the unit (1) of the instant application, wherein R_1 is a hydrogen atom or a methyl group, n=1 and m=0.

Tert-butyl (meth)acrylate is equivalent to the unit (3) of the instant application, wherein R_4 is a hydrogen atom or methyl group and R_5 - R_7 are methyl groups.

Claims 24 and 25 refer only to the intended use of the composition of claim 23 and such intended use adds no patentable weight to the claim.

Therefore, the composition of Hamada et al. meets the limitations of claims 24-25 of the instant application.

With regard to claim 28, Hamada et al. disclose that the composition may comprise a basic compound, said basic compound controlling the diffusion of an acid generated from an acid generator upon exposure to light (par.0029).

With regard to claim 29, Hamada et al. disclose that the acid generator (C) may be a 4-t-butylphenyl diphenylsulfonium trifluoromethanesulfonate (par.0027).

Art Unit: 1795

6. Claims 23-32 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ohta et al. (US Pg-Pub 2004/0038148) in view of Aoai et al. (US Patent 6,245,485).

Page 5

With regard to claim 23, Ohta et al. disclose a positive type radiation sensitive resin composition, said composition comprising (A) a polymer having an acid-dissociative functional group which is dissociated with an acid to generate an acid functional group and (B) a component which generates an acid when irradiated with radiation (abstract). The composition further comprises a solvent (par.0146-0148).

The resin (A) comprises a monomer (I) represented by the formula (I):

(I) (formula (1) in par.0027), wherein R_1 is a hydrogen atom or a methyl group and R^2 is a monovalent alycyclic group of 6 to 20 carbon atoms which may have a substituent or a monovalent aromatic group of 6 to 20 carbon atoms which may have a substituent (par.0028-0029).

The resin (A) may further comprise other repeating units (monomers (II)), and examples of monomers (II) include amido group-containing vinyl compounds, such as acrylamide and methacrylamide and aromatic vinyl compounds (par.0043), such as isopropenylphenol (par.0039, 0046).

Art Unit: 1795

While Ohta et al. do not specifically disclose a polymer comprising a unit of monomer (I) of formula (I) above and units derived from monomers (II), such as isopropenylphenol and acrylamide/methacrylamide, it would have been obvious to one of ordinary skill in the art at the time of the invention to obtain such copolymer, based on Ohta's teachings regarding the monomer (I) and the monomers (II) which can copolymerize with monomer (I) (par.0027-0028, 0037, 0039, 0043).

However, Ohta et al. do not specifically disclose the acrylamide and methacrylamide compounds used as monomers (II) in the resin (A).

Aoai et al. disclose a positive resin composition comprising a compound generating an acid on irradiation of an active light ray or radiation, a resin (abstract).

Aoai et al. teach that the resin comprises a group which decomposes by the action of an acid to increase the solubility in an alkali developer (column 9, lines 35-38). The resin may comprise copolymerizable monomers, such as acrylamides and methacrylamides (column 53, lines 22-27), wherein the acrylamides include N-hydroxyphenyl acrylamide (column 53, lines 59-61) and the methacrylamides include N-hydroxyphenyl methacrylamides (column 54, lines 6-7).

Aoai et al. specifically teach that monomers capable of increasing alkali solubility, such as N-(hydroxyphenyl)acrylamide and N-(hydroxyphenyl)methacrylamide are preferred (column 54, line 61 - column 55, line 2).

Art Unit: 1795

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to use N-(hydroxyphenyl)acrylamide and N-(hydroxyphenyl)methacrylamide as comonomers for the resin (A) of Ohta et al., as taught by Aoai et al., in order to improve the solubility of the resin used in a positive type resist composition.

The monomer (I) of formula (I) of Ohta et al. is equivalent to the unit (3) of the instant application.

N-(hydroxyphenyl)acrylamide is equivalent to the unit (1) of the instant application, wherein R_1 is a hydrogen atom, n, m=0.

N-(hydroxyphenyl)methacrylamide is equivalent to the unit (1) of the instant application, wherein R_1 is a methyl group, n, m=0.

Claims 24 and 25 refer only to the intended use of the composition of claim 23 and such intended use adds no patentable weight to the claim.

Therefore, the composition of Ohta modified by Aoai meets the limitations of claims 24-25 of the instant application.

With regard to claim 26, Ohta et al. disclose that the acid generator (B) is comprised in an amount of 0.1 to 20 parts by weight, preferably 0.3 to 10 parts by weight based on 100 parts by weight of the resin (A) (par.0117).

The solvent is comprised in the radiation sensitive composition in an amount preferably between 20 to 60 parts by weight based on 100 parts by weight of positive radiation sensitive composition (par.0149).

Art Unit: 1795

With regard to claim 27, Ohta et al. further disclose that the positive-type radiation sensitive composition may further comprise an alkali-soluble resin, other than the resin (A) (par.0126).

With regard to claim 28, Ohta et al. disclose that the positive-type radiation sensitive composition may further comprise an acid diffusion inhibitor, which is preferably a nitrogen-containing organic compound (par.0119-0120).

With regard to claim 29, Ohta et al. disclose that the acid generating agent (B) may be 4-t-butylphenyl diphenylsulfonium trifluoromethanesulfonate, 4-t-butylphenyl diphenylsulfonium perfluro-n-octanesulfonate, 4-t-butylphenyl diphenylsulfonium pyrenesulfonate, 4,7-di-n-butoxynaphthyltetrahydrophenium trifluoromethanesulfonate (par.0115).

With regard to claims 30-31, Ohta et al. disclose that the positive-type radiation sensitive composition can be applied on a support film to form a resin film (par.0151) and the thickness of the resin film can be varied depending upon the use application of the product formed by plating. In case of a bump, the thickness of the resin film is in the range of 20 to 100 μ m (par.0160).

With regard to claim 32, Ohta et al. disclose a process comprising the following steps:

- applying the positive-type radiation sensitive composition onto a substrate having a conductive layer (such as aluminium, copper, silver, gold, palladium and alloys of two or more kinds of these metals, as disclosed in par.0156) on its surface and drying to form a resin film;
 - exposing, heating and developing the resin film to obtain a pattern;

- electroplating using the pattern formed on the substrate as a mold;
- removing the resin film portion from the substrate, and
- removing the conductive layer present on the area of the substrate other than the area where the product formed by plating has been formed (par.00153).

Response to Arguments

7. Applicant's arguments filed on July 11, 2008 with respect to the new claims 23-32 have been considered but are moot in view of the new grounds of rejection.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to ANCA EOFF whose telephone number is (571)272-9810. The examiner can normally be reached on Monday-Friday, 6:30 AM-4:00 PM, EST.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Cynthia H. Kelly can be reached on 571-272-1526. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

nformation regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through

Application/Control Number: 10/593,812 Page 10

Art Unit: 1795

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/A. E./ Examiner, Art Unit 1795

/Cynthia H Kelly/ Supervisory Patent Examiner, Art Unit 1795